SGS-THOMSON MICROELECTRONICS

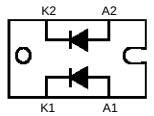
STTA9012T(V)1/2

TURBOSWITCH ™ "A". ULTRA-FAST HIGH VOLTAGE DIODE

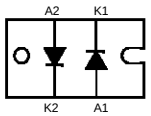
PRELIMINARY DATA

MAIN PRODUCTS CHARACTERISTICS

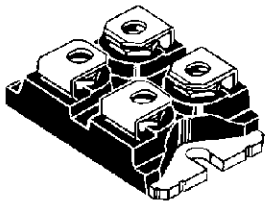
$I_{F(AV)}$	**45A**
V_{RRM}	**1200V**
t_{rr} (typ)	**65ns**
V_F (max)	**1.85V**



STTA9012T(V)1



STTA9012T(V)2



ISOTOP ®
(Plastic)
Screw version (*)

FEATURES AND BENEFITS

- ULTRA-FAST, SOFT AND NOISE-FREE RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY AND/OR HIGH PULSED CURRENT OPERATIONS.

DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V.
TURBOSWITCH 1200V drastically cuts losses in all high voltage operations which require extremely fast, soft and noise-free power diodes. Due to their optimized switching performances they also highly decrease power losses in any associated switching IGBT or MOSFET in all "Freewheel Mode" operations.
They are particularly suitable in Motor Control circuitries, or in the primary of SMPS as snubber, clamping or demagnetizing diodes, and also at the secondary of SMPS as high voltage rectifier diodes.
Packaged in ISOTOP®, this 1200V device is particularly intended for use on 3 phase 400V industrial mains.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	1200	V
V_{RSM}	Non repetitive peak reverse voltage	1200	V
$I_{F(RMS)}$	RMS forward current	150	A
I_{FRM}	Repetitive peak forward current (tp = 5 µs, f = 5kHz)	900	A
T_j	Max operating junction temperature	150	°C
T_{stg}	Storage temperature	-65 to 150	°C

(*) : Tin plasted Fast-on version is also available (Without V suffix).

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THERMAL AND POWER DATA

Symbol	Parameter	Conditions	Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	Per diode	0.85	°C/W
		Total	0.48	
		Coupling	0.1	
P_1	Conduction power dissipation (see fig. 6)	$I_{F(AV)}$ = 45A δ =0.5 Per diode Tc= 70°C	94	W
P_{max}	Total power dissipation Pmax = P1 + P3 (P3 = 10% P1)	Per diode Tc= 62°C	104	W

STATIC ELECTRICAL CHARACTERISTICS (see Fig.6)

Symbol	Parameter	Test Conditions		Min	Typ	Max	Unit
V_F *	Forward voltage drop	I_F =45A	Tj = 25°C Tj = 125°C			2.05 1.85	V V
I_R **	Reverse leakage current	V_R =0.8 x V_{RRM}	Tj = 25°C Tj = 125°C			200 12	µA mA

Test pulses widths : * tp = 380 µs, duty cycle < 2%
** tp = 5 ms , duty cycle < 2%

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING (see Fig.7)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	Tj = 25°C I_F = 0.5 A I_R = 1A Irr = 0.25A I_F = 1 A dI_F/dt =-50A/µs V_R =30V		65	115	ns
I_{RM}	Maximum reverse recovery current	Tj = 125°C VR = 600V I_F =45A dI_F/dt = -360 A/µs dI_F/dt = -500 A/µs		TBD	TBD	A
S factor	Softness factor	Tj = 125°C V_R = 600V I_F =45A dI_F/dt = -500 A/µs		1.2		/

TURN-ON SWITCHING (see Fig.8)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	Tj = 25°C I_F =45 A, dI_F/dt = 360 A/µs measured at, 1.1 × $V_F$max			TBD	ns
V_{Fp}	Peak forward voltage	Tj = 25°C I_F =45A, dI_F/dt = 360 A/µs I_F =40A, dI_F/dt = 500 A/µs			TBD TBD	V

APPLICATION DATA

The 1200V TURBOSWITCH series has been designed to provide the lowest overall power losses in all high frequency or high pulsed current operations. In such applications (Fig 1 to 5),the way of calculating the power losses is given below :

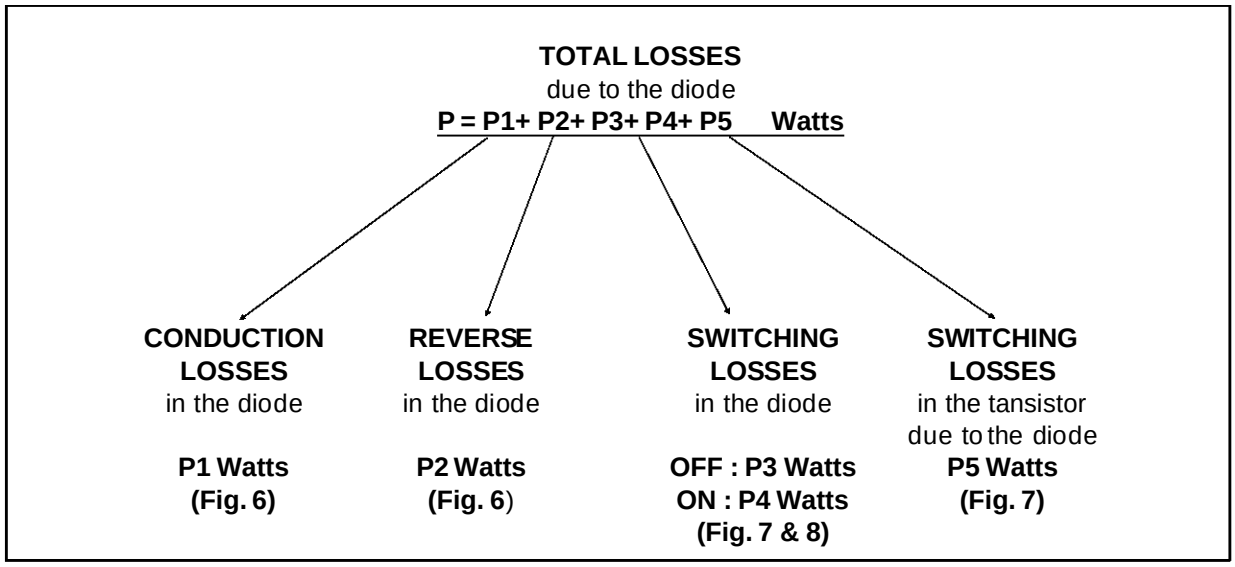


Fig. 1 : "FREEWHEEL" MODE.

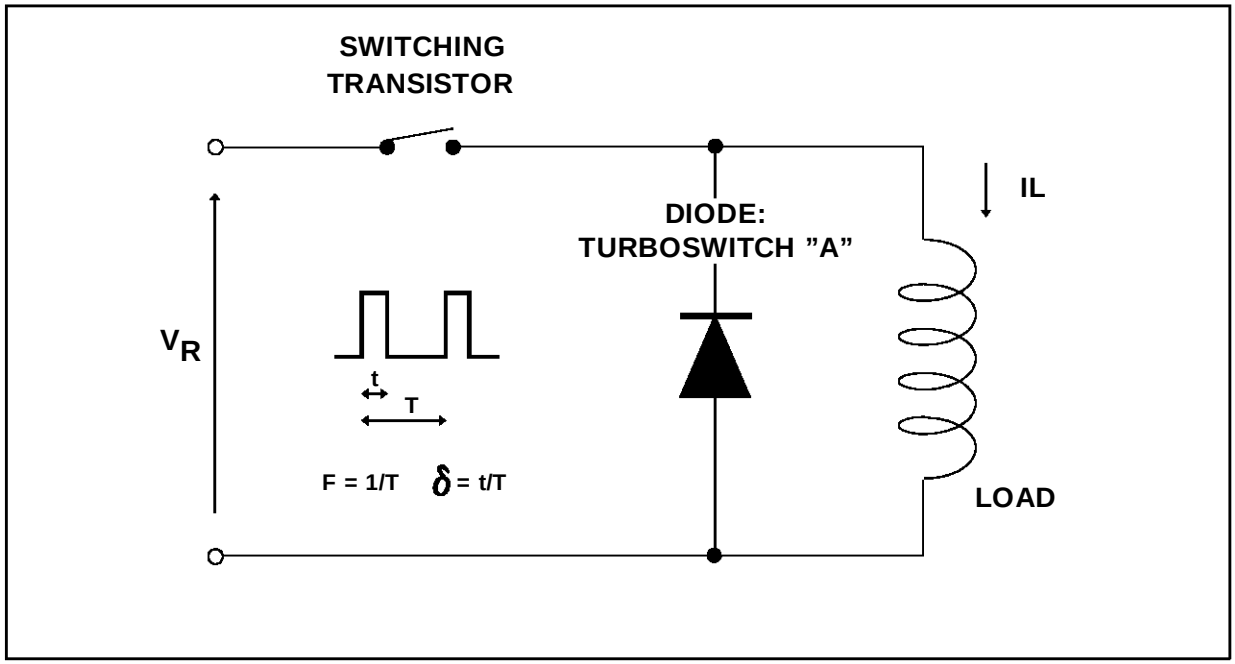


Fig. 2 : SNUBBER DIODE.

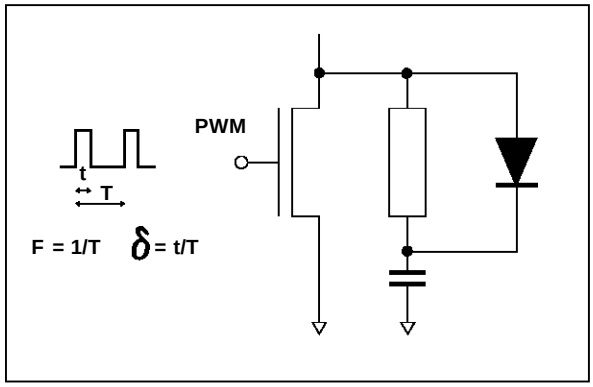


Fig. 3 : CLAMPING DIODE.

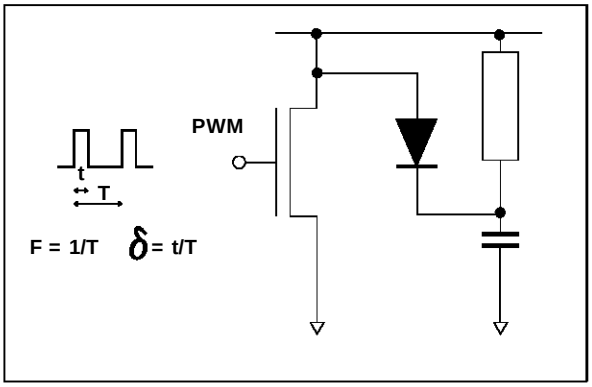


Fig. 4 : DEMAGNETIZING DIODE.

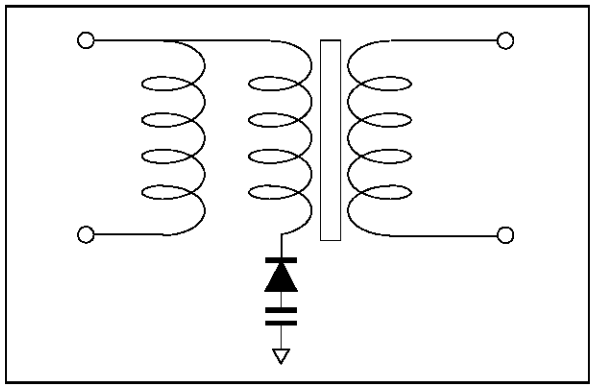
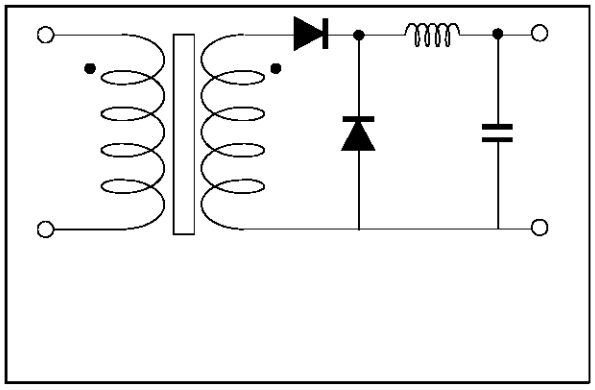
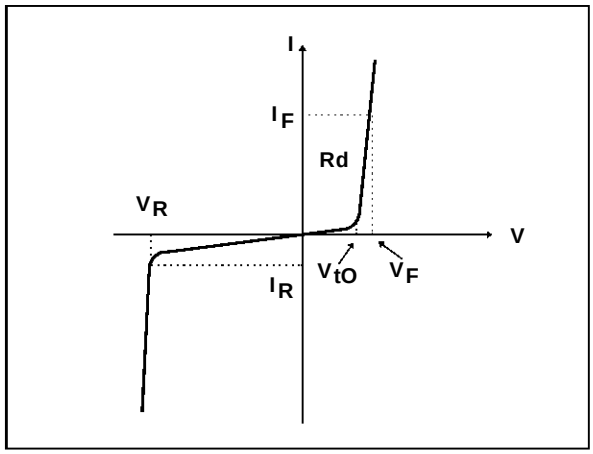


Fig. 5 : RECTIFIER DIODE.



STATIC & DYNAMIC CHARACTERISTICS . POWER LOSSES .

Fig. 6: STATIC CHARACTERISTICS



Conduction losses :

$P1 = V_{t0} . I_{F(AV)} + R_d . I_F{}^2{}_{(RMS)}$

with

$V_{t0} = 1.57$ V

$R_d = 0.006$ Ohm

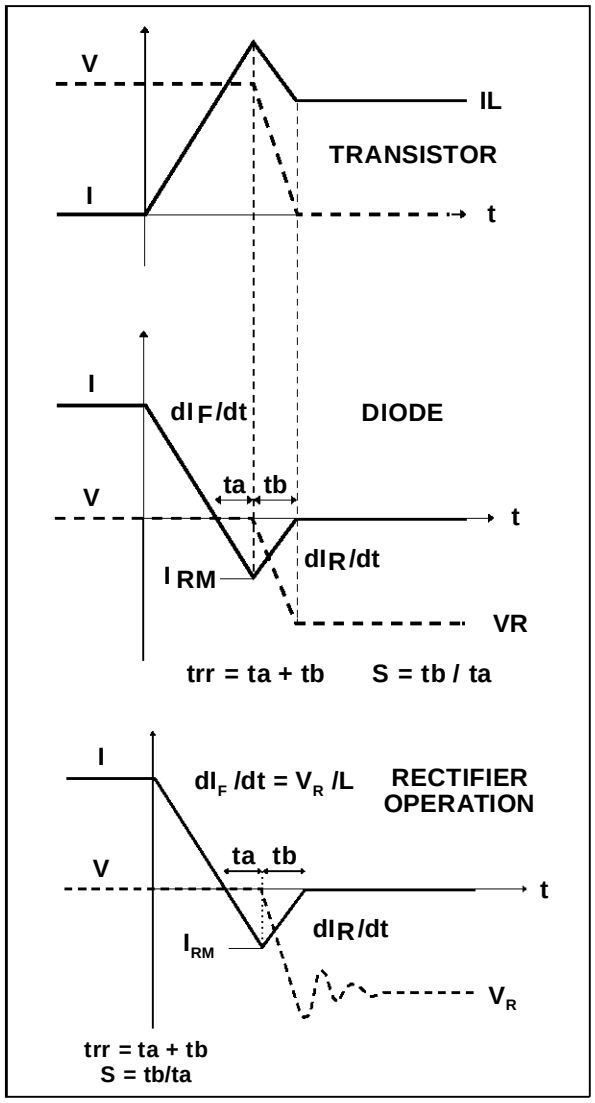
(Max values at 125°C,suitable for Ipeak < $3.I_{F(av)}$)

Reverse losses :

$P2 = V_R . I_R . (1 - \delta)$

APPLICATION DATA (Cont'd)

Fig. 7: TURN-OFF CHARACTERISTICS



Turn-on losses :
(in the transistor, due to the diode)

$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

Turn-off losses (in the diode) :

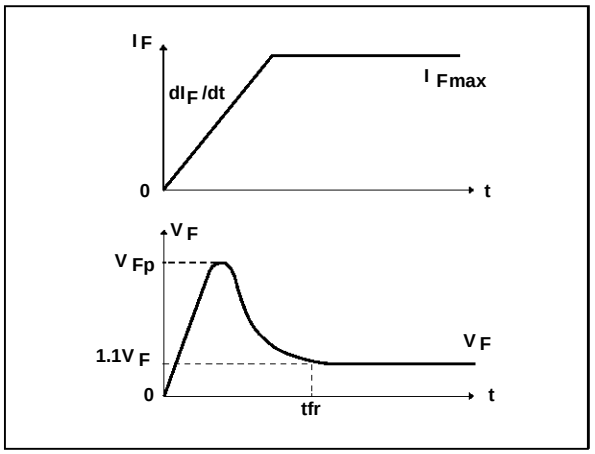
$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

Turn-off losses :
(with non negligible serial inductance)

$$P3' = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt} + \frac{L \times I_{RM}^2 \times F}{2}$$

P3,P3' and P5 are suitable for power MOSFET and IGBT

Fig. 8: TURN-ON CHARACTERISTICS

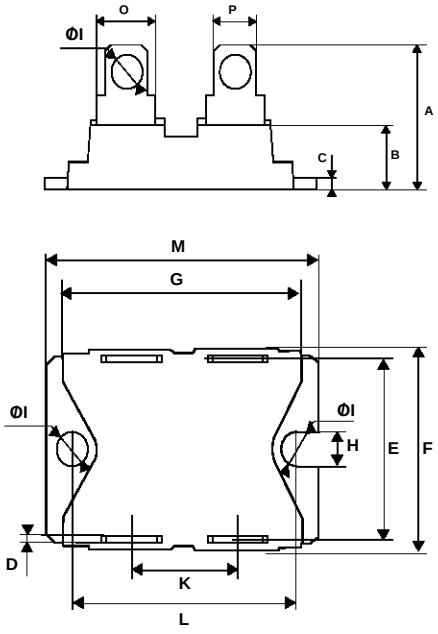


Turn-on losses :

$P4 = 0.4\ (V_{FP} - V_F)\ .\ I_{Fmax}\ .\ t_{fr}\ .\ F$

PACKAGE MECHANICAL DATA

ISOTOP Fast on version



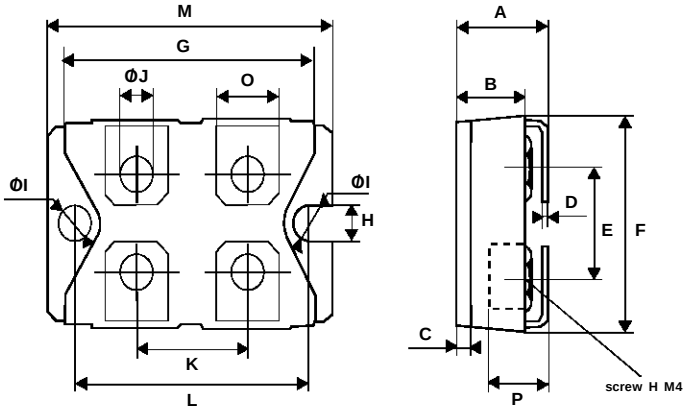
REF.	DIMENSIONS			
	Millimeters		Inchesz	
	Min.	Max.	Min.	Max.
A	20.30	20.70	0.799	0.815
B	8.90	9.10	0.350	0.358
C	1.958	2.05	0.078	0.081
D	0.75	0.87	0.029	0.034
E	22.00	22.40	0.866	0.882
F	25.10	25.50	0.988	1.004
G	31.50	31.70	1.240	1.248
H	4.00		1.57	
I	4.10	4.30	0.161	0.169
J	2.50	2.60	0.098	1.103
K	14.90	15.10	0.580	0.595
L	30.10	30.30	1.185	1.193
M	37.80	38.20	1.488	1.504
N	4.10	4.30	0.161	0.169
O	7.80	8.20	0.307	0.323
P	6.20	6.40	0.244	0.252

Cooling method : C
Marking : Type number
Weight : 28 g

- Recommended torque value : 1.3 N.m (MAX 1.5 N.m) for the 6 x M4 screws. (2 x M4 screws recommended for mounting the package on the heatsink and the 4 screws given with the screw version).
- The screws supplied with the package are adapted for mounting on a board (or other types of terminals) with a thickness of 0.6 mm min and 2.2 mm max.

PACKAGE MECHANICAL DATA

ISOTOP Screw version



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	11.80	12.20	0.465	0.480
B	8.90	9.10	0.350	0.358
C	1.95	2.05	0.077	0.081
D	0.75	0.85	0.029	0.034
E	12.60	12.80	0.496	0.504
F	25.10	25.50	0.988	1.004
G	31.50	31.70	1.240	1.248
H	4.00		0.157	
I	4.10	4.30	0.161	0.169
J	4.10	4.30	0.161	0.169
K	14.90	15.10	0.586	0.595
L	30.10	30.30	1.185	1.193
M	37.80	38.20	1.488	1.504
O	7.80	8.20	0.307	0.323
P	5.50		0.216	

Cooling method : C
Marking : Type number
Weight : 28 g